PRODUCTION CHANGES FOR PORTABLE RECEIVER MODELS 4ER27A1-3,11-13 REV. H 4ER27B1-3,11-13 REV. P

Changes listed below are identified by the letter appearing in the REV. Pad on the receiver chassis.

REV. A - resistors changed to improve performance. Transistors changed to agree with changes in vendor designations.

Part Changed	Was	Changed To
Q302	Transistor, G-E Type 4JD3B4	Transistor, G-E Type 4JD3B4 or 4JX3B504.
Q303 thru Q305	Transistor, G-E Type 2N450	Transistor, G-E Type 2N450 or 4JX1A810.
G301-R1,R5 and G302-R1,R5	Resistor: composition 6200 ohms ±5%, 1/4 watt. G-E Part No. C-3R152-P662J.	Resistor, composition 3900 ohms ±10%, 1/4 watt. G-E Part No. C-3R152-P392K.
G301-R3,R7 and G302-R3,R7	Resistor; composition 4700 ohms ±10%, 1/4 watt. G-E Part No. C-3R152-P472K.	Resistor; composition 2200 ohms ±10%, 1/4 watt. G-E Part No. C-3R152-P220K.
G301-R4,R8 and G302-R4,R8	Resistor; composition 3900 ohms ±10%, 1/4 watt. G-E Part No. C-3R152-P392K.	Resistor; composition 2200 ohms ±10%, 1/4 watt. G-E Part No. C-3R152-P222K.
Z301-Q1	Transistor; G-E Type 4JD3B5.	Transistor; G-E Type 4JD3B5 or 4JX3B505.

REV. B - To prevent oscillator stoppage at low end of band.

Part Changed	Was	Changed To
G301-C2 and G302-C6	Capacitor; ceramic disk, insulated, temp. compensating; 7.0 mmfd ±0.25 mmfd, 500 VDCW. G-E Dwg. C-5494210-P38.	Capacitor; ceramic disk, compensating 15 mmfd ±0.25 mmfd, 500 VDCW. G-E Dwg. No. C-5494210-P244.

REV.	C -	To	improve	receiver	sensitivity
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Part Changed	Was	Changed To
Z303-R11, and Z303-R16.	Resistor: composition 3300 ohms ±10%, 1/4 watt. G-E Part. No. C-3R152-332K.	Resistor: composition 2200 ohms ±10%, 1/4 watt. G-E Part No. C-3R152-222K.

REV. D - To decrease collector current.

Part Changed	Was	Changed To
G301-R1 and G302-R5	Resistor: composition 3900 ohms ±10%, 1/10 w. G-E Part No. C-3R151-P392K.	Resistor: composition 2200 ohms ±10%, 1/4 w. G-E Part No. C-3R152-P222K.
G301-R3 G302-R3 G302-R7	Resistor: composition 2200 ohms ±10%, 1/4 w. G-E Part No. C-3R152-P222K.	Resistor: composition 3900 ohms ±10%, 1/10 w. G-E Part No. C-3R151-P392K.

REV. E - To increase audio high-frequency response. To reduce standby current drain.

Part Changed	Was	Changed To
RT301	Thermistor: 10 ohms. ±10% max input watts 1.0 at 40° C, temp coefficient 1400 ±10%. Similar to Globar Type 781F. G-E Dwg. No.	Thermistor: 30 ohms
	B-5490828-P1	No. B-5490828-P2
R330	Resistor: composition 750 ohms ±5%, 1/2 w. G-E Part No. C-3R77-P751J.	Resistor: composition 2700 ohms ±10%, 1/2 w. G-E Part No. C-3R77-P272K
C326	Capacitor: Mylar dielectric, 0.22 mfd ±20%, 100 VDCW. Similar to Goodall Electric Co. Type 663-UW. G-E Dwg. No. B-7491930-P110.	Deleted.

REV. F - Improves limiter action and reduces audio distortion at high modulation levels.

REV. F (Cont')

Part Changed	Was	Changed To
Z302-C8	Capacitor: ceramic Hi-K disk, insulated, 0.025 mfd +80% -20%, 50 VDCW. Sprague Cat. #29C187. G-E Dwg. No. B-7491827-P3.	Capacitor: mylar dielec- tric; 0.01 mfd ±20%, 50 VDCW. Similar to Goodall Type 601PE. G-E Dwg. No. B-5491189-P105.
Z302-C9 Z303-C4 Z303-C7 Z303-C10 Z303-C13 Z303-C14	Capacitor: ceramic, Hi-K disk, insulated; 0.1 mfd, +80%, -30% 50 VDCW. Sprague Cat. #36C172. G-E Dwg. No. B-7491827-P5.	Capacitor: mylar dielec- tric; 0.022 mfd ±20% 100 VDCW. Similar to Goodall Type 663-UW. G-E Dwg. B-7491930-P6.

Elementary Diagram Changes

Changed delineation of parts as follows:

Z302-C8, .025 MFD to Z302-C8, .01 MFD)
Z302-C9, .1 MFD to Z302-C9, .022 MF	ď
Z303-C4, .1 MFD to Z303-C4, .022 MF	ď
Z303-C7, .1 MFD to Z303-C7, .022 MF	'D
Z303-C10, .1 MFD to Z303-C10, .022 MF	
Z303-C13, .1 MFD to Z303-C13, .022 MF	
Z303-C14, .1 MFD to Z303-C14, .022 MF	'D

REV. A (Models 4ER27A1,2,3,11,12,13 only) REV. G (Models 4ER27B1,2,3,11,12,13 only)

Purpose of Change - To improve RF sensitivity of the receiver.

Part Changed	Was	Changed To
Q301 XQ301 R301	$3N36\\ A-7162500-P1\\ Resistor, composition\\ 6200 ohms \pm 5\%,\ 1/10 \ w.\\ G-E\ Dwg.\ No.\\ C-3R151-P622J.$	2N502 B-5490277-P1 Resistor, composition 1800 ohms ±10%, 1/10 w. G-E Dwg. No. C-3R151-P912J.
Т302	Resistor, composition 4700 ohms ±10%, 1/10 w. G-E Dwg. No. C-3R151-P472K.	Resistor, composition 9100 ohms ±10%, 1/10 w. G-E Dwg. No. C-3R151-P912J.
R303	Resistor, composition 8200 ohms ±10%, 1/2 w. G-E Dwg. No. C-3R77-P822K.	Resistor, composition, 820 ohms, ±10%, 1/2 w. G-E Dwg. No. C-3R77-P821K.

REV. A and REV. G (Cont'd)

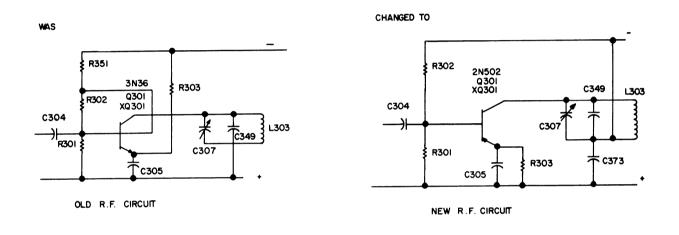
Part Changed Was Changed To

C373 Added. Capacitor, ceramic disc; insulated, 2000 uuf, ±10%. G-E Dwg. No. C-5494481-P114.

R351

Resistor, composition, 2700 Deleted. ohms, $\pm 5\%$, 1/10 w. G-E Dwg. No. C-3R151-P272J.

Elementary Diagram Changes



REV. B (Models 4ER27A1,2,3,11,12,13 only) REV. H (Models 4ER27B1,2,3,11,12,13 only)

Purpose of Change - To eliminate chance of instability in front end of the receiver.

Part Changed	Was	Changed To
L302	Coil G-E Part No. PL-4031073-G2.	Deleted
L304	Coil, G-E Part No. PL-4031073-G3.	Coil, G-E Part No. PL-4031073-G2.
L315	Added	Coil, G-E Part No. PL-4031073-G5.

REV. C (Models 4ER27A1,2,3,11,12,13 only) REV. J (Models 4ER27B1,2,3,11,12,13 only)

Purpose of Change - To improve audio response.

REV. C and REV. J (Cont'd)

Part Changed	Was	Changed To
R323	Resistor, composition, 5600 ohms ±10%, 1/4 w. G-E Dwg. No. C-3R152-P562K.	Resistor, composition, 4700 ohms ±10%, 1/4 w. G-E Dwg. No. C-3R152-P472K.
C305	Capacitor; ceramic disc, insulated, 2000 mmfd ±10% 500 VDCW. RMC Type JF Discap. G-E Dwg. No. C-5494481-P114.	Capacitor; ceramic disc, 2000 mmfd ±10%, 500 VDCW. RMC Type JF Discap. G-E Dwg. No. C-5494481-P14.

REV. D (Models 4ER27A1-3,11-13 only) REV. K (Models 4ER27B1-3,11-13 only)

Purpose of Change - To optimize design in consideration of component variations.

Part Changed	<u>Was</u>	Changed To
R323	Resistor, composition, 4700 ohms, ±10%, 1/4 w. G-E Dwg. No. C-3R152-P472K.	Resistor, composition, 5100 ohms, ±5%, 1/4 w. G-E Dwg. No. C-3R152-P512J.

REV. E (Models 4ER27A1-3,11-13 only) REV. L (Models 4ER27B1-3,11-13 only)

To stabilize discriminator idling for varying input signal level.

Part Changed	Was	Changed To
Z303-Q4 and	Transistor, Type 2N450/ 4JX1A552	Transistor, Type 2N188A.
Z303-Q5		

Elementary Diagram Changes

Changed reference to Z303-Q4 and Z303-Q5 from 2N450/4JX1A552 to 2N188A.

REV. F (Models 4ER27A1-3,11-13 only) REV. M (Models 4ER27B1-3,11-13 only)

To protect front end Transistor against overload due to excessive voltage on antenna which might be induced from an external course.

REV. F and REV. M (Cont'd)

Part Changed

Was

Changed To

CR305

Added

Diode, hermetically sealed glass body, max. inverse working volts 50V. Forward voltage drop at 10 ma - Min. 0.34 v max 0.37 v Similar to Radio Receptor Type No. DR385. G-E Dwg. & Part No. A-4034827-G1.

Elementary Diagram Changes

Added Part No. CR305 between top 2 on L315 and ground. Added L315 top 2 which is same as top 1 except it is located 2 1/2 turns from bottom of coil. Added Note 1: The polarity of CR305 is unimportant.

REV. G (Models 4ER27A1-3,11-13 only)

REV. N (Models 4ER27B1-3,11-13 only)

To improve mixer operation, and to make use of a more available transistor.

Part Changed

Was

Changed To

Z301-Q1

Transistor, Germanium tetrode Transistor, Germanium, NPN. NPN. G-E Dwg. & Part No. G-E Dwg. & Part No. A-4036546-P2.

A-4036929-P2.

Elementary Diagram Changes

Removed Base-2 of Z301-Q1.

REV. H (Models 4ER27A1-3.11-13 only)

REV. P (Models 4ER27B1-3,11-13 only)

To improve operation of receivers at high humidity by improving the moisture resisting treatment of the filter coils.

Elementary Diagram Changes

None.

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